# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



### **SMD Schottky Barrier Diode**

-Designed for mounting on small surface.

-Case: 1005/SOD-323F standard package

-Terminals: Gold plated, solderable per

-Polarity: Indicated by cathode band.

MIL-STD-750, method 2026.

-Extremely thin / leadless package.

-Majority carrier conduction.

molded plastic.

**CDBF0530** lo = 500 mA VR = 20 Volts RoHS Device

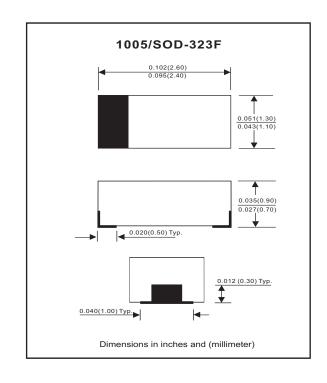
-Low forward voltage.

**Mechanical data** 

-Mounting position: Any

-Weight: 0.006 gram(approx.).

**Features** 



#### Maximum Rating (at TA=25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Peak reverse voltage		Vrm			30	V
Reverse voltage		Vr			20	V
Average forward rectified current		lo			0.5	А
Forward current,surge peak	8.3 ms single half sine-wave superimposed on rate load (JEDEC method)	Ifsm			2	А
Storage temperature		Тѕтс	-40		+125	°C
Junction temperature		Tj			+125	°C

#### Electrical Characteristics (at TA=25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Forward voltage	IF = 100mA IF = 500mA	VF			0.36 0.47	V
Reverse current	VR = 20V	Ir			100	uA
Capacitance between terminals	f = 1 MHz, and 0 VDC reverse voltage	Ст		100		pF



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#### RATING AND CHARACTERISTIC CURVES (CDBF0530)

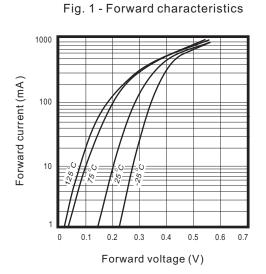
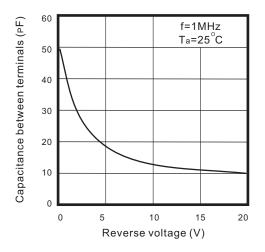


Fig. 3 - Capacitance between terminals characteristics



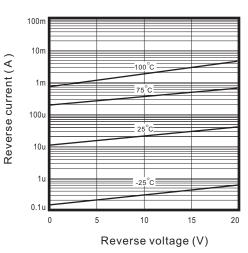
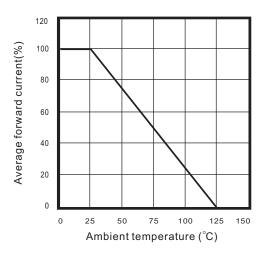


Fig.4 - Current derating curve



#### Fig. 2 - Reverse characteristics